Art Unit: 2186

DETAILED ACTION

Claim Rejections - 35 USC § 103

 The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

- The factual inquiries set forth in *Graham v. John Deere Co.*, 383 U.S. 1, 148
 USPQ 459 (1966), that are applied for establishing a background for determining obviousness under 35 U.S.C. 103(a) are summarized as follows:
 - 1. Determining the scope and contents of the prior art.
 - 2. Ascertaining the differences between the prior art and the claims at issue.
 - 3. Resolving the level of ordinary skill in the pertinent art.
 - Considering objective evidence present in the application indicating obviousness or nonobviousness.
- Claims 1-6, 8-10, 12-19 and 24-25 are rejected under 35 U.S.C. 103(a) as being unpatentable over Baddiley (US 4,852,065), and further in view of Anderson et al. (US 2004/0111567).
- 4. Consider claim 1, Baddiley discloses a multi-ported orthogonal data memory for effecting a corner-turning function, where for example data input as a sequence of bit-parallel word-serial data transfers are converted to data output in a bit-serial, word-parallel fashion; the memory being arranged to transfer data words comprising a plurality of data items (fig. 2, abstract, Col. 1 lines 4-30 and Col. 3 lines 20-50, where a data item is considered to be a data word or some portion of a data word.) and

Art Unit: 2186

comprising: a plurality of data memory cells arranged in the form of a matrix having rows and columns, wherein the memory further comprises a plurality of different and non-sequential groups of memory cells within the matrix (fig. 2, where the reorganization unit of fig. 2 is considered the memory, each buffer of the memory is in the form of a matrix with rows and columns and a plurality of different and nonsequential groups of memory cells is considered buffers 20 and 21.), each group being: i) a subgroup of the total number of memory cells in the matrix (fig. 2, where each buffer is a subgroup of the total number of memory cells in the matrix.), ii) having members of the group located in different rows and in different columns of the matrix (fig. 2, Col. 3) lines 20-58, where each bit position is considered a member and each one is located across different rows and columns that make up each buffer.), and iii) being individually addressable to effect transfer of a data word thereto (fig. 2, Col. 3 lines 20-58, Each RAM component of each buffer contains 512 individually addressable locations); and enabling means having dedicated strobe connections to each of the plurality of groups of memory cells and being arranged to exclusively enable memory cells belonging to a selected ones of the plurality of groups, as determined by the size of the data items being transferred, to read all of the data items of the data word present at their inputs into the selected group of memory cells or to write all of the data items of the data word stored in the selected group of memory cells to their outputs in a single transfer operation (Fig. 2 and 3, Col. 3 lines 20-58 and Col. 5 lines 1-10, where each buffer, and the number of addressable locations within the buffer, is selected after a determination of/based on the size of the data items is made and the arrangement of the data in the

Art Unit: 2186

buffer is effected by the word size. Each buffer has dedicated connections for reading out and writing in data words as shown in fig. 2 and 3 and a write or read operation is considered a single transfer operation.).

Baddiley does not explicitly disclose that the claimed single transfer operation occurs in a single clock cycle. But Anderson et al. does teach that it is conventional for a multi-port memory devices to be able to read and write data in a single clock cycle (pg. 1 ¶ [0010]) and further that the improved multiport-memory of Anderson can also perform read and write access operations in one clock cycle, this improved multiport-memory can provide a significant reduction in chip area for a given memory storage capacity.

It would have been obvious to one of ordinary skill in the art at the time of the invention for the multi-ported memory of Baddiley to be able to perform read and write operations in one clock cycle, because Anderson et al. teaches that conventional multi-port memories can perform read and write accesses to data in one clock cycle (pg. 1 ¶ [0010]) and further because the improved multiport-memory of Anderson can also perform read and write access operations in one clock cycle, this improved multiport-memory can provide a significant reduction in chip area for a given memory storage capacity (pg. 1 ¶ is [0010] and [0011]).

Consider claim 2, Baddiley in view of Anderson et al. discloses a memory
according to Claim 1, wherein each of the groups of memory cells is specified
according to its use in transferring the data items of the data word to or from the matrix

to effect the corner-turning function (Baddiley: Col. 3 lines 20-58, each buffer is designated to either be a write or read buffer).

- 6. Consider claim 3, Baddiley in view of Anderson et al. discloses a memory according to Claim 1, wherein the enabling means comprises selection means for selecting the current size of the data items in the data word and configuring the enabling means to operate with the selected current size of data items (Baddiley: Col. 5 lines 1-10, where the size of the data items in the word is considered the size of the data items together that make up the whole word).
- 7. Consider claim 4, Baddiley in view of Anderson et al. discloses a memory according to Claim 3, wherein the number of different groups of memory cells provided within the matrix equals the number of different sizes of data items which can be handled by the memory (Baddiley: Fig. 2, col. 3 lines 20-50 and Col. 5 lines 1-10, where a group of memory cells can be considered any subset of memory cells of a buffer that spans multiple rows and columns and word sizes of 32 bits or lower can be used by the system, therefore since a group is merely defined as spanning multiple rows and columns, the number of groups can be equal to the number of sizes available).
- Consider claim 5, Baddiley in view of Anderson et al. Discloses a memory
 according to Claim 3, wherein each item of the data word being transferred is an integer
 power-of-two multiple of eight bits (Baddiley: Col. 5 lines 1-10).
- Consider claim 6, Baddiley in view of Anderson et al. discloses a memory according to Claim 1, wherein the memory is arranged to operate with different types of

Art Unit: 2186

data words, each type comprising 64, 32, 16 or 8-bit data items (Baddiley: Col. 5 lines 1-10).

- 10. Consider claim 8, Baddiley in view of Anderson et al. discloses a memory according to Claim 7, wherein the enabling means is arranged to enable a selected group upon a set of logic conditions becoming true, the logic conditions being determined from a current selected row of the matrix and the size of the items being transferred (Baddiley: fig. 2 and 4, Col. 3 lines 20-59 and Col. 5 lines 1-10, where logic conditions include the decoder using the control and address bits to select particular rows or columns in a particular buffer).
- 11. Consider claim 9, Baddiley in view of Anderson et al. discloses a memory according to Claim 1, wherein the enabling means comprises a pointer in a shift register (38) for determining which rows of the matrix are to be enabled for taking part in the data transfer of all of the data items of the data word (Baddiley: Fig. 4, Col. 3 lines 50-59, Col. 4 lines 33-37, where register 45 comprises a reference to counter 40 and is used in determining the control and address bits to enable particular rows of the matrix).
- 12. Consider claim 10, Baddiley in view of Anderson et al. discloses a memory according to Claim 9, wherein the pointer in the shift register (38) is configured to be operable in a plurality of different modes, each mode corresponding to a possible size of the data item being transferred, the pointer being configured within a single instruction to advance by a predetermined number of bit positions as determined by the current mode thereby indicating which rows of the matrix are to be enabled to facilitate transfer of the whole of the data word to or from the matrix (Baddiley: fig. 4, Col. 3 lines

Art Unit: 2186

30-59, col. 4 lines 33-37 and Col. 5 lines 1-10, where register 45 determines word size and address and control bits to indicate rows and columns of a matrix to facilitate transfer of data words).

- 13. Consider claim 12, Baddiley in view of Anderson et al. discloses a memory according to Claim 9, further comprising means for converting the current position of the row pointer in the shift register (38) to one or more row select logic signals (Baddiley: Fig. 4, Col. 3 lines 50-59, Col. 4 lines 33-37, where register 45 comprises a reference to counter 40 and is used in determining the control and address bits to enable particular rows of the matrix).
- 14. Consider claim 13, Baddiley in view of Anderson et al. discloses a memory according to Claim 12, further comprising a hard-wired backward propagation network for determining, from the bit position of the pointer and the size of the current data items, the rows of the matrix that are to be enabled for the data transfer (Baddiley: Fig. 4, Col. 3 lines 50-59, Col. 4 lines 33-37, where register 45 comprises a reference to counter 40 and is used in determining the control and address bits to enable particular rows of the matrix, the components of fig. 4 perform the functions claimed to be performed by the hard-wired backward propagation network).
- 15. Consider claim 14, Baddiley in view of Anderson et al. discloses a memory according to Claim 1, wherein the enabling means comprises byte column determining means for enabling a specific group of byte column locations of the matrix within a selected word row to be enabled for transferring an item of the data word across a word port of the memory (Baddiley: Fig. 3-4 Col. 4 lines 6-46 and Col. 5 lines 45-62, where

register 46 comprises a reference to counter 41 and is used in determining the control and address bits to enable particular columns of the matrix and 43 determines which buffer is being referenced by which register/counter combination).

- 16. Consider claim 15, Baddiley in view of Anderson et al. discloses a memory according to Claim 14, wherein the byte column determining means comprises a table specifying the relationship between the plurality of different groups of memory cells and their respective memory cell locations in the matrix (Baddiley: fig. 3-4, Col. 3-4 lines 29-41 and 59-33 and Col. 5 lines 45-62, where register's 40 and 41 consist of a linear table of bits with indicate a particular row/column for reading or writing information in a particular buffer).
- 17. Consider claim 16, Baddiley in view of Anderson et al. discloses a memory according to Claim 1, wherein the enabling means comprises bit column determining means for enabling a specific group of bit column locations of the matrix within a selected word row to be enabled for transferring a bit of an item of the data word across a bit port of the memory (Baddiley: Fig. 3-4 Col. 4 lines 6-46 and Col. 5 lines 45-62, where register 46 comprises a reference to counter 41 and is used in determining the control and address bits to enable particular columns of the matrix and 43 determines which buffer is being referenced by which register/counter combination).
- 18. Consider claim 17, Baddiley in view of Anderson et al. discloses a memory according to Claim 16, wherein the bit column determining means comprises a table specifying the relationship between the plurality of different groups of memory cells and their respective memory cell locations in the matrix (Baddiley: fig. 3-4, Col. 3-4 lines 29-

Art Unit: 2186

41 and 59-33 and Col. 5 lines 45-62, where register's 40 and 41 consist of a linear table of bits with indicate a particular row/column for reading or writing information in a particular buffer).

- 19. Consider claim 18, Baddiley in view of Anderson et al. discloses a memory according to Claim 1, wherein the locations of the memory cells of each group form a repeating pattern when viewed as a matrix (Baddiley: fig. 2).
- 20. Consider claim 19, Baddiley in view of Anderson et al. discloses a memory according to Claim 1, further comprising a load register (42) arranged to retain temporarily bit-serial word parallel data transferred to and from the matrix of memory cells across a bit port of the memory (Baddiley: Fig. 3 and Col. 4 lines 20-25).
- 21. Consider claim 24, Baddiley in view of Anderson et al. discloses a memory according to Claim 2, wherein the enabling means comprises selection means for selecting the current size of the data items in the data word and configuring the enabling means to operate with the selected current size of data items (Baddiley: Col. 5 lines 1-10, where the size of the data items in the word is considered the size of the data items together that make up the whole word).
- 22. Consider claim 25, Baddiley in view of Anderson et al. discloses a memory according to Claim 3, wherein the enabling means comprises a pointer in a shift register (38) for determining which rows of the matrix are to be enabled for taking part in the data transfer of all of the data items of the data word (Baddiley: Fig. 4, Col. 3 lines 50-59, Col. 4 lines 33-37, where register 45 comprises a reference to counter 40 and is used in determining the control and address bits to enable particular rows of the matrix).

Art Unit: 2186

Claim Rejections - 35 USC § 103

23. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

- 24. The factual inquiries set forth in *Graham v. John Deere Co.*, 383 U.S. 1, 148 USPQ 459 (1966), that are applied for establishing a background for determining obviousness under 35 U.S.C. 103(a) are summarized as follows:
 - 1. Determining the scope and contents of the prior art.
 - 2. Ascertaining the differences between the prior art and the claims at issue.
 - Resolving the level of ordinary skill in the pertinent art.
 - Considering objective evidence present in the application indicating obviousness or nonobviousness.
- 25. Claim 11 is rejected under 35 U.S.C. 103(a) as being unpatentable over Baddiley (US 4,852,065) in view of Anderson et al. (US 2004/0111567) as applied to claim 9 above, and further in view of Kim et al. (US 6,781,898 B2).
- 26. Consider claim 11, Baddiley in view of Anderson et al. discloses a memory according to Claim 9, Baddiley in view of Anderson et al. does not disclose what happens if a faulty row exists in the matrix, however Kim et al. does teach the following claimed features: storing information relating to a faulty row in the matrix and wherein the shifting word pointer register (38) is arranged to be controlled to skip the faulty row in the matrix and instead point to otherwise redundant additional row of the matrix (abstract, Col. 1 lines 40-46 and Col. 2 lines 8-23).

Art Unit: 2186

It would have been obvious to one of ordinary skill in the art at the time of the invention to include the teachings of Kim et al. with that of Baddiley and Anderson et al., because Kim teaches that detecting and skipping defective rows in a memory and then using an additional redundant row in its place, doing this improves memory yield and ensures proper operation of the memory (abstract, Col. 1 lines 23-46 and Col. 2 lines 8-23).

- 27. Claims 20-23 are rejected under 35 U.S.C. 103(a) as being unpatentable over Baddiley (US 4,852,065) in view of Anderson et al. (US 2004/0111567) as applied to claim 1 above, and further in view of Glover (US 5,581,773).
- 28. Consider claim 20, Baddiley in view of Anderson et al. discloses a memory according to Claim 1, but does not discuss the use of a mask register, however Glover does disclose the claimed features of: a first masking register (44) arranged to mask bits of the data to be read out of the matrix of memory cells via a bit port of the memory (Col. 4 lines 11-14 and 65-67 and Col. 10 lines 57-62).

It would have been obvious to one of ordinary skill in the art at the time of the invention to include the teachings of Glover with that of Baddiley in view of Anderson et al., because Glover teaches that using the PE's and register's in the manner discloses can exclude the need for special corner turning hardware and allow for more PE's per chip therefore yielding significantly greater implementation economies and reduce cost and complexity (Col. 1 lines 43-55 and Col. 2 lines 37-67).

 Consider claim 21, Baddiley in view of Anderson et al. discloses a memory according to Claim 1, but does not discuss the use of a mask register, however Glover

Art Unit: 2186

does disclose the claimed features of: a second masking register (46) arranged to mask bits of the data to be input to the matrix of memory cells via a bit port of the memory (Col. 4 lines 11-14 and 65-67 and Col. 10 lines 57-62).

It would have been obvious to one of ordinary skill in the art at the time of the invention to include the teachings of Glover with that of Baddiley in view of Anderson et al., because Glover teaches that using the PE's and register's in the manner discloses can exclude the need for special corner turning hardware and allow for more PE's per chip therefore yielding significantly greater implementation economies and reduce cost and complexity (Col. 1 lines 43-55 and Col. 2 lines 37-67).

30. Consider claim 22, Baddiley disclose a multi-ported orthogonal data memory for effecting a data corner-turning function between a plurality of processors and location addressable data store, the memory being arranged to transfer input data words comprising a plurality of data items across a word port for the data store and transfer data bits comprising an output word across a bit port for the processors (fig. 2, abstract, Col. 1 lines 4-30 and Col. 3 lines 20-50, where a data item is considered to be a data word or some portion of a data word.), the memory comprising: a plurality of data memory cells arranged in the form of a matrix having rows and columns, wherein the memory further comprises a plurality of different and non-sequential groups of memory cells within the matrix (fig. 2, where the reorganization unit of fig. 2 is considered the memory, each buffer of the memory is in the form of a matrix with rows and columns and a plurality of different and non-sequential groups of memory cells is considered buffers 20 and 21.), wherein each group: i) a subgroup of the total number

of memory cells in the matrix (fig. 2, where each buffer is a subgroup of the total number of memory cells in the matrix.), ii) having members of the group located in different rows and in different columns of the matrix (fig. 2, Col. 3 lines 20-58, where each bit position is considered a member and each one is located across different rows and columns that make up each buffer.), iii) relates to a different size of data item (fig. 2, Col. 3 lines 20-58 and Col. 5 lines 1-10, each group can be used to handle words of 32-bit size or smaller based on preset values and therefore each group is related to data items of a different size.) and iv) is individually addressable to effect transfer of a data word thereto (fig. 2, Col. 3 lines 20-58, Each RAM component of each buffer contains 512 individually addressable locations); and enabling means having dedicated strobe connections to each of the plurality of groups of memory cells and being arranged to exclusively enable memory cells belonging to a selected ones of the plurality of groups, as determined by the size of the data items being transferred, to transfer all of the data items of the input data word via the word port into the selected group or bit data representing an output data word stored in the selected group via the bit port in a single transfer operation (Fig. 2 and 3, Col. 3 lines 20-58 and Col. 5 lines 1-10, where each buffer, and the number of addressable locations within the buffer, is selected after a determination of/based on the size of the data items is made and the arrangement of the data in the buffer is effected by the word size. Each buffer has dedicated connections for reading out and writing in data words as shown in fig. 2 and 3 and a write or read operation is considered a single transfer operation.).

Art Unit: 2186

Baddiley uses an array of processing elements, but does not explicitly disclose whether these processing elements are SIMD processors, however Glover does teach the use of an array of processing elements just like in Baddiley that utilize SIMD processors (Col. 1 lines 13-55 and Col. 2 lines 28-42)

It would have been obvious to one of ordinary skill in the art at the time of the invention to include the teachings of Glover with that of Baddiley, because Glover teaches that SIMD processors are frequently used to process image data, just as the processor array in Baddiley is designed to do, therefore being a common and well-known (Col. 1 lines 41-43).

Baddiley does not explicitly disclose that the claimed single transfer operation occurs in a single clock cycle. But Anderson et al. does teach that it is conventional for a multi-port memory devices to be able to read and write data in a single clock cycle (pg. 1 ¶ [0010]) and further that the improved multiport-memory of Anderson can also perform read and write access operations in one clock cycle, this improved multiport-memory can provide a significant reduction in chip area for a given memory storage capacity.

It would have been obvious to one of ordinary skill in the art at the time of the invention for the multi-ported memory of Baddiley to be able to perform read and write operations in one clock cycle, because Anderson et al. teaches that conventional multi-port memories can perform read and write accesses to data in one clock cycle (pg. 1 ¶ [0010]) and further because the improved multiport-memory of Anderson can also perform read and write access operations in one clock cycle, this improved multiport-

memory can provide a significant reduction in chip area for a given memory storage capacity (pg. 1 ¶'s [0010] and [0011]).

Consider **claim 23**, as applied to **claim 1** above, Baddiley in view of Anderson et al. uses an array of processing elements, but does not explicitly disclose whether these processing elements are SIMD processors, however Glover does teach the use of an array of processing elements just like in Baddiley that utilize SIMD processors (Col. 1 lines 13-55 and Col. 2 lines 28-42)

It would have been obvious to one of ordinary skill in the art at the time of the invention to include the teachings of Glover with that of Baddiley in view of Anderson et al., because Glover teaches that SIMD processors are frequently used to process image data, just as the processor array in Baddiley is designed to do, therefore being a common and well-known (Col. 1 lines 41-43).

Response to Arguments

- Applicant's arguments filed 10/19/2011 have been fully considered but they are not persuasive.
- 32. The Applicant's arguments pertaining to the newly amended claim limitations have been addressed by the Examiner's updated explanation and rejection of these claims and limitations.
- 33. The Applicant further argues the limitation: "having members of the group located in different rows and in different columns of the matrix". However, as explained further in the rejection of this limitation: each bit position is considered a member and each one is

located in different rows and columns that make up each buffer. This interpretation is considered reasonable and thus is maintained.

- 34. The Applicant also argues that Baddiley does not disclose enabling particular groups of data memory cells in response to the size of the data items. The limitation being referred to by this argument requires enabling of memory cells belonging to a selected group and the amount of memory cells enabled is dependent on the size of the data. As stated in the rejections of claims 1 and 22 above, that the number of addressable locations enabled for a read or write of a buffer is based on the size of the data word being used at the time, which meets the claim requirements.
- 35. The Applicant further argues the limitation: "a subgroup of the total number of memory cells in the matrix". However, as explained further in the rejection of this limitation: each buffer is a subgroup of the total number of memory cells in the matrix of the reorganization apparatus. This interpretation is considered reasonable and thus is maintained.
- 1. In response to applicant's argument that: "In fact, the system disclosed by Baddiley requires four clock cycles to transfer a single 32-bit word. Quadrupling the clock speed to four times the input data word rate, as disclosed by Baddiley, in order to compensate for a smaller memory buffer, teaches away from "a single transfer operation comprising a single clock cycle," as recited in claim 1 of the present application.", the test for obviousness is not whether the features of a secondary reference may be bodily incorporated into the structure of the primary reference; nor is it that the claimed invention must be expressly suggested in any one or all of the

Art Unit: 2186

references. Rather, the test is what the combined teachings of the references would have suggested to those of ordinary skill in the art. See *In re Keller*, 642 F.2d 413, 208 USPQ 871 (CCPA 1981). The Anderson et al. reference clearly states that it is conventionally known that multi-port memories can perform read and write accesses to data in one clock cycle (pg. 1 ¶ [0010]) and that the improved multiport-memory of Anderson et al. can also perform read and write access operations in one clock cycle, this improved multiport-memory can provide a significant reduction in chip area for a given memory storage capacity (pg. 1 ¶ s [0010] and [0011]). The motivation conveys to one of ordinary skill in the art that the ability of a multi-port memory to perform reads and writes in one clock cycle is well-known and advantageous and thus is considered proper.

Conclusion

 THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of

Art Unit: 2186

the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to MICHAEL ALSIP whose telephone number is (571)270-1182. The examiner can normally be reached on Monday through Thursday 9:00AM to 4:00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matt Kim can be reached on 571-272-4182. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Michael Alsip Primary Examiner Art Unit 2186

/Michael Alsip/ Primary Examiner, Art Unit 2186

Art Unit: 2186

October 31, 2011